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April 2016

MMBF5434 N-Channel Switch

Features

- · This device is designed for digital switching applications where very low on resistance is mandatory.
- · Sourced from Process 58.



1. Drain 2. Source 3. Gate

Ordering Information

Part Number	Top Mark	Package	Packing Method
MMBF5434	61Z	SSOT 3L	Tape and Reel

Absolute Maximum Ratings(1), (2)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{DG}	Drain-Gate Voltage	25	V
V_{GS}	Gate-Source Voltage	-25	V
I _{GF}	Forward Gate Current	10	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to 150	°C

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

Thermal Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Max.	Unit
P _D	Total Device Dissipation	350	mW
	Derate Above 25°C	2.8	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient ⁽³⁾	556	°C/W

Notes:

3. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit	
Off Characteristics						
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_G = -1 \mu A, V_{DS} = 0$	-25		V	
I _{GSS}	Gate Reverse Current	$V_{GS} = -15 \text{ V}, V_{DS} = 0$		200	nA	
V _{GS} (off)	Gate-Source Cut-Off Voltage	$V_{DS} = 5 \text{ V}, I_D = 3\text{nA}$	-1.0	-4.0	V	
I _D (off)	Gate-Source Cutoff Voltage	$V_{DS} = 5.0, V_{GS} = -10 \text{ V}$		200	pА	
On Characteristics						
I _{DSS}	Zero-Gate Voltage Drain Current ⁽⁴⁾	V _{DS} = 15 V, I _{GS} = 0	30		mA	
r _{DS} (on)	Drain-Source On Resistance	$V_{GS} = 0, I_D = 10 \text{ mA}$		10	Ω	
Small Signal Characteristics						
C _{iss}	Input Capacitance	$V_{DS} = 0$, $V_{GS} = 10$ V, $f = 1.0$ MHz		30	pF	
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = 0$, $V_{GS} = 10$ V, $f = 1.0$ MHz		15	pF	

Note:

4. Pulse test: pulse width \leq 300 μ s, duty cycle \leq 2%.

Typical Performance Characteristics

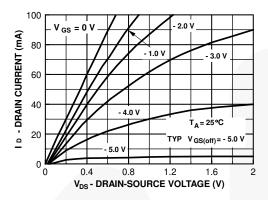


Figure 1. Common Drain-Source

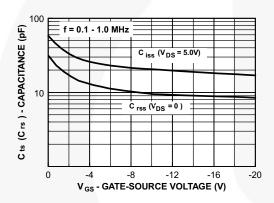


Figure 3. Common Drain-Source

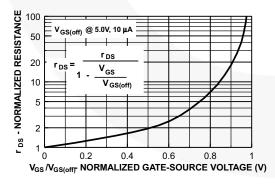


Figure 5. Normalized Drain Resistance vs. Bias Voltage

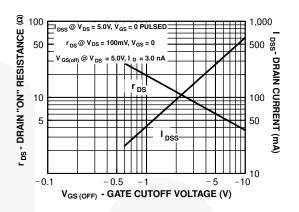


Figure 2. Parameter Interactions

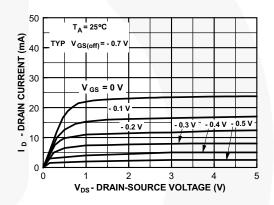


Figure 4. Common Drain-Source

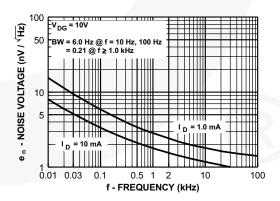


Figure 6. Noise Voltage vs. Frequency

Typical Performance Characteristics (Continued)

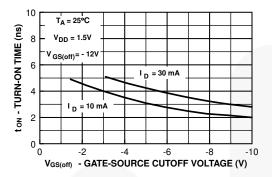


Figure 7. Switching Turn-On Time vs.
Gate-Source Cut-Off Voltage

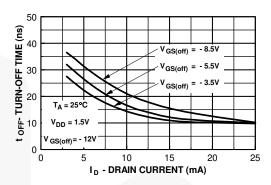


Figure 8. Switching Turn-On Time vs. Drain Current

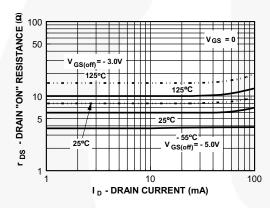


Figure 9. On Resistance vs. Drain Current

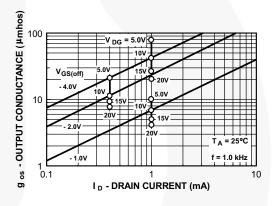


Figure 10. Output Conductance vs. Drain Current

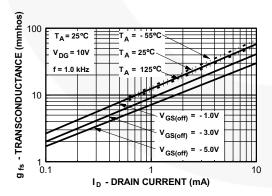


Figure 11. Transconductance vs. Drain Current

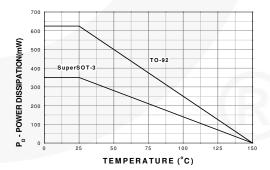
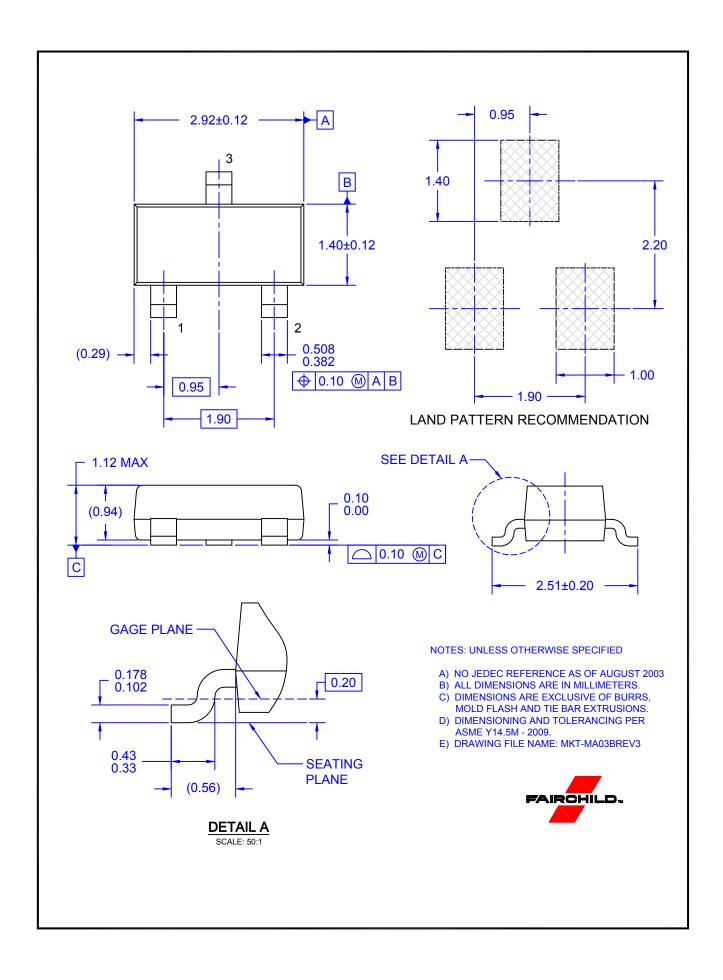


Figure 12. Power Dissipation vs.
Ambient Temperature



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